

PATENT ABSTRACTS OF JAPAN

(11)Publication number : 2002-111059

(43)Date of publication of application : 12.04.2002

(51)Int.CI.

H01L 33/00

H01S 5/343

(21)Application number : 2000-299755

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(22)Date of filing : 29.09.2000

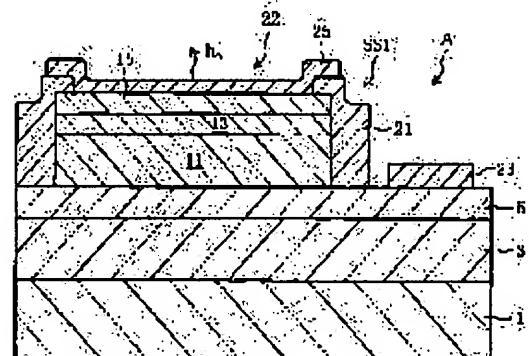
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(54) OPTICAL SEMICONDUCTOR ELEMENT AND OPTICAL SEMICONDUCTOR DEVICE

(57)Abstract:

PROBLEM TO BE SOLVED: To prevent positive holes from overflowing to an n type clad layer of an optical semiconductor element and to prevent the light guide-out efficiency from decreasing.

SOLUTION: This element includes an n type $Mg_xZn_{1-x}O$ clad layer 5, an $In_yGa_{1-y}N$ active layer 11 formed thereupon, a p type $Mg_zZn_{1-z}O$ clad layer 15 formed thereupon, a 1st electrode 23 which electrically forms a contact for the clad layer 5, and a 2nd electrode 25 which electrically forms a contact for the clad layer 15.



LEGAL STATUS

[Date of request for examination]

[Date of sending the examiner's decision of rejection]

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

[Date of registration]

[Number of appeal against examiner's decision of

rejection]

[Date of requesting appeal against examiner's
decision of rejection]

[Date of extinction of right]

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